



UF4001 - UF4007

ULTRAFAST RECOVERY RECTIFIER DIODES

VOLTAGE RANGE: 50 - 1000V

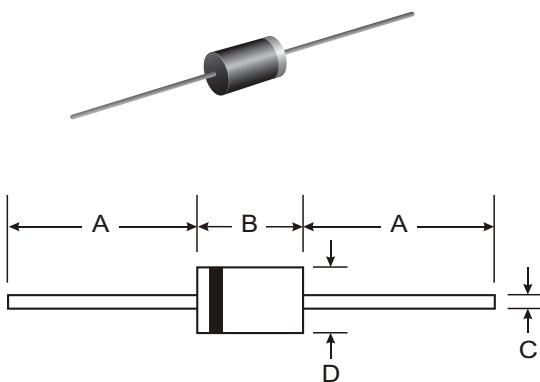
CURRENT: 1.0 A

Features

- Diffused Junction
- Low Forward Voltage Drop
- High Current Capability
- High Reliability
- High Surge Current Capability

Mechanical Data

- Case: D O - 4 1 Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: Cathode Band
- Weight: 0.34 grams (approx.)
- Mounting Position: Any
- Marking: Type Number



DO-41		
Dim	Min	Max
A	25.40	—
B	4.06	5.21
C	0.71	0.864
D	2.00	2.72

All Dimensions in mm

Maximum Ratings and Electrical Characteristics $T_A = 25^\circ\text{C}$ unless otherwise specified

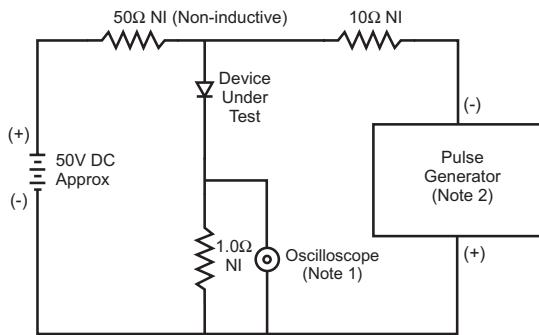
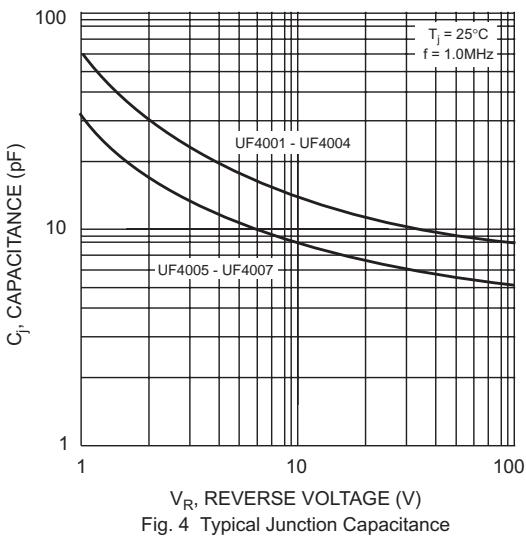
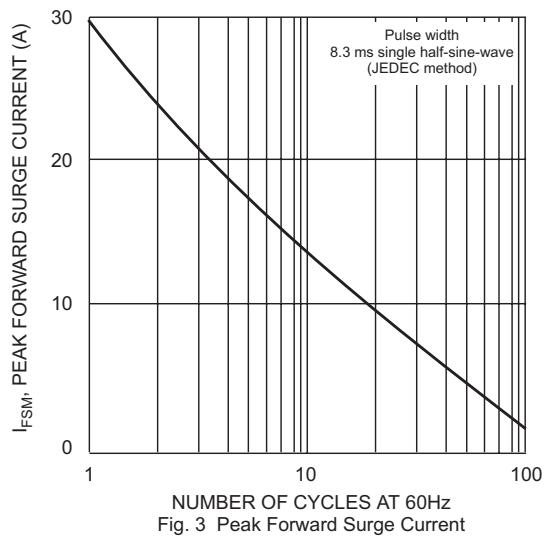
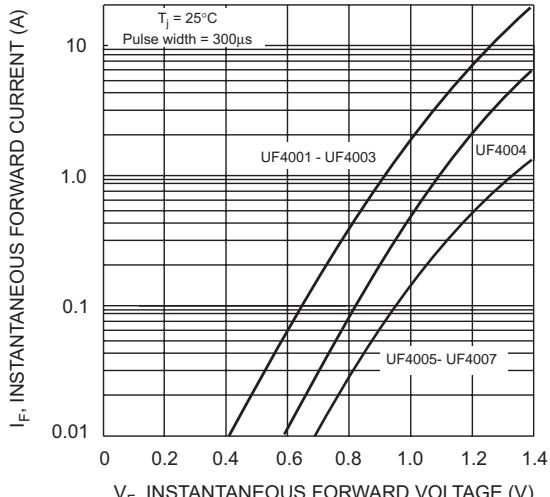
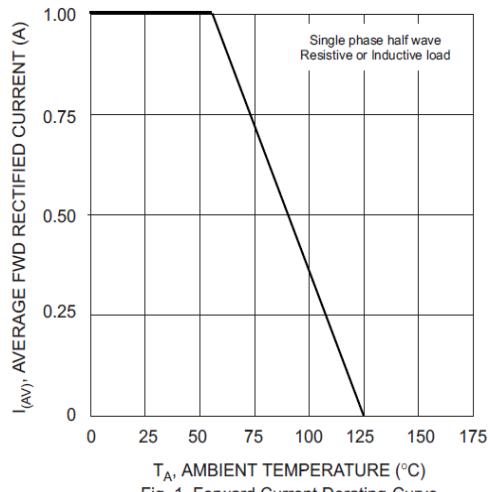
Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	UF 4001	UF 4002	UF 4003	UF 4004	UF 4005	UF 4006	UF 4007	Unit			
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	VRRM VRWM VR	50	100	200	400	600	800	1000	V			
RMS Reverse Voltage	VR(RMS)	35	70	140	280	420	560	700	V			
Average Rectified Output Current (Note 1) $\text{@ } T_A = 55^\circ\text{C}$	I _O	1.0							A			
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	30							A			
Forward Voltage $\text{@ } I_F = 1.0\text{A}$	V _{FM}	1.0		1.3	1.7		1.7		V			
Peak Reverse Current $\text{@ } T_A = 25^\circ\text{C}$ At Rated DC Blocking Voltage $\text{@ } T_A = 100^\circ\text{C}$	I _{RM}	5.0 100							μA			
Reverse Recovery Time (Note 2)	t _{rr}	50			75			nS				
Typical Junction Capacitance (Note 3)	C _j	20			10			pF				
Operating Temperature Range	T _j	-65 to +125							$^\circ\text{C}$			
Storage Temperature Range	T _{STG}	-65 to +150							$^\circ\text{C}$			

Note: 1. Leads maintained at ambient temperature at a distance of 9.5mm from the case

2. Measured with IF = 0.5A, IR = 1.0A, IRR = 0.25A. See figure 5.

3. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.



- Notes:
1. Rise Time = 7.0ns max. Input Impedance = 1.0MΩ, 22pF.
 2. Rise Time = 10ns max. Input Impedance = 50Ω.

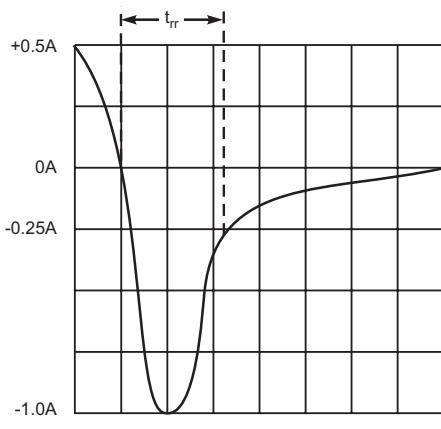


Fig. 5 Reverse Recovery Time Characteristic and Test Circuit

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